

ES1A - ES1G

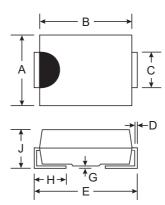
1.0A SURFACE MOUNT SUPER-FAST RECTIFIER

Features

- Glass Passivated Die Construction
- Super-Fast Recovery Time For High Efficiency
- Low Forward Voltage Drop and High Current Capability
- Surge Overload Rating to 30A Peak
- Ideally Suited for Automated Assembly
- Lead Free Finish/RoHS Compliant (Note 5)

Mechanical Data

- Case: SMA
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Lead Free Plating (Matte Tin Finish). Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number & Date Code: See Below
- Ordering Information: See Below
- Weight: 0.064 grams (approximate)



SMA					
Dim	Min	Max			
Α	2.29	2.92			
В	4.00	4.60			
С	1.27	1.63			
D	0.15	0.31			
Е	4.80	5.59			
G	0.10	0.20			
н	0.76	1.52			
J	2.01	2.30			
All Dimensions in mm					

Maximum Ratings and Electrical Characteristics @ T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%

Characteristic		Symbol	ES1A	ES1B	ES1C	ES1D	ES1G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R	50	100	150	200	400	V
RMS Reverse Voltage		V _{R(RMS)}	35	70	105	140	280	V
Average Rectified Output Current	@ $T_T = 110^{\circ}C$	lo	1.0				Α	
Non-Repetitive Peak Forward Surge C 8.3ms Single half sine-wave Superimp (JEDEC Method)	urrent osed on Rated Load	I _{FSM}			30			A
Forward Voltage Drop	@ I _F = 0.6A @ I _F = 1.0A	V _{FM}	0.90 0.98			1.25	V	
Peak Reverse Current at Rated DC Blocking Voltage	@ $T_A = 25^{\circ}C$ @ $T_A = 100^{\circ}C$	I _{RM}	5.0 200				μA	
Reverse Recovery Time (Note 1)		t _{rr}			25		35	ns
Typical Total Capacitance (Note 2)		Ст			10			pF
Typical Thermal Resistance, Junction to Terminal (Note 3)		R _{θJT}	40				°C/W	
Operating and Storage Temperature R	ange	Tj, T _{STG}			-65 to +150			°C

Ordering Information (Note 4)

Device*	Packaging	Shipping
ES1x-13-F	SMA	5000/Tape & Reel

Notes: 1. Measured with I_F = 0.5A, I_R = 1.0A, I_{rr} = 0.25A. See figure 5.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Unit mounted on PC board with 5.0 mm² (0.013 mm thick) copper pad as heat sink.

4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf. *x = Device type, e.g. ES1A-13-F.

5. RoHS revision 13.2.2003. Glass and High Temperature Solder Exemptions Applied, see EU Directive Annex Notes 5 and 7.

Marking Information



XXXX = Product type marking code, ex. ES1A)''= Manufacturers' code marking YWW = Date code marking Y = Last digit of year ex: 2 for 2002 WW = Week code 01 to 52

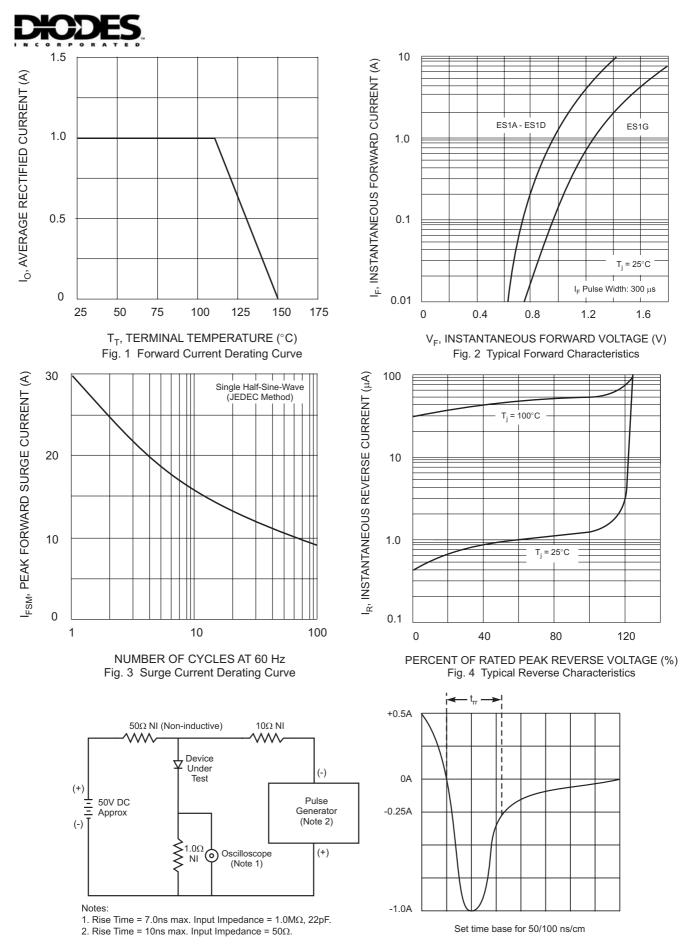


Fig. 5 Reverse Recovery Time Characteristic and Test Circuit



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